NSN 5961-01-012-2947

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-012-2947 **Inclosure Material:** Plastic **Overall Length:** 0.340 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.230 inches **Mounting Method: Terminal Semiconductor Material:** Gallium arsenide phosphide Voltage Rating In Volts Per Characteristic: 2.8 forward voltage, peak **Current Rating Per Characteristic:** 40.00 milliamperes all primaries preset **Power Rating Per Characteristic:** 115.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 105.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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